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March 2016



FQB34P10

P-Channel QFET® MOSFET

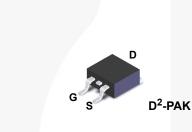
100 V, -33.5 A, 60 mΩ

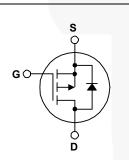
Description

This P-Channel enhancement mode power MOSFET is • -33.5 A, -100 V, $R_{DS(on)}$ = 60 m Ω (Max.) @ V_{GS} = .10 V, produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- I_D = -16.75 A
- Low Gate Charge (Typ. 85 nC)
- Low Crss (Typ. 170 pF)
- 100% Avalanche Tested
- · 175°C Maximum Junction Temperature Rating





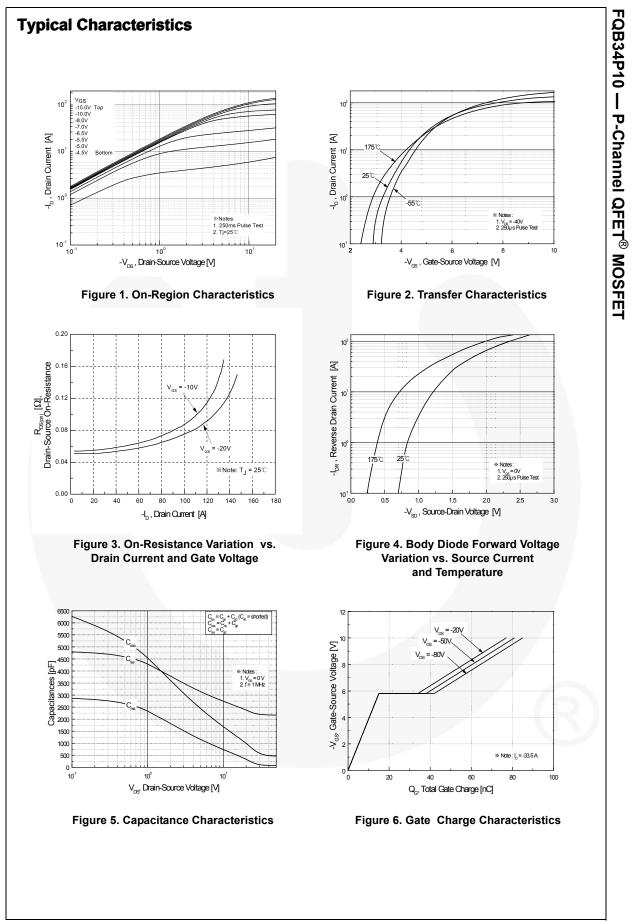
Absolute Maximum Ratings T_c = 25°C unless otherwise noted.

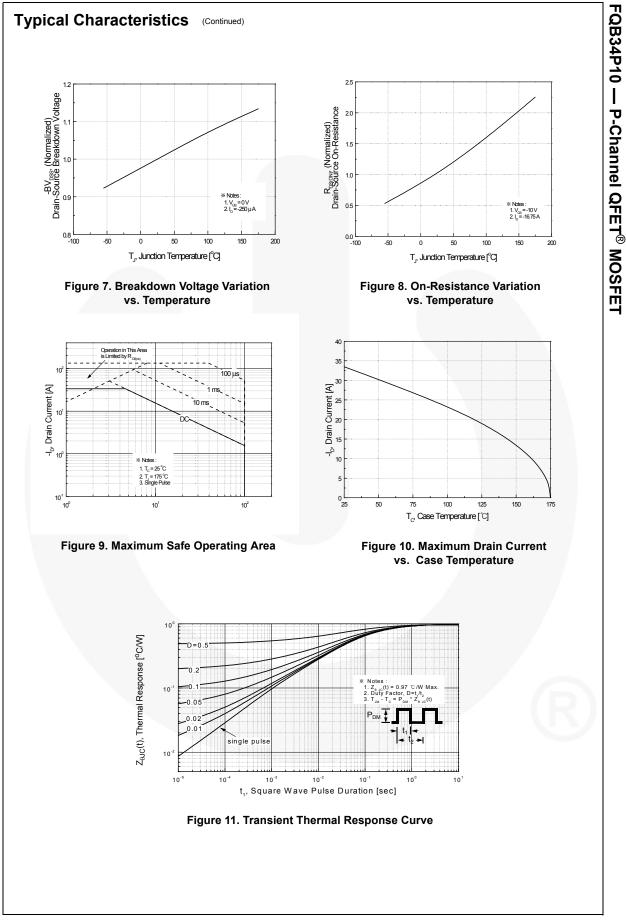
Symbol	Parameter	FQB34P10TM	Unit	
V _{DSS}	Drain-Source Voltage		-100	V
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		-33.5	A
	- Continuous (T _C = 100°C)	-23.5	A	
I _{DM}	Drain Current - Pulsed	(Note 1)	-134	A
V _{GSS}	Gate-Source Voltage		± 25	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	2200	mJ
I _{AR}	Avalanche Current	(Note 1)	-33.5	A
E _{AR}	Repetitive Avalanche Energy	(Note 1)	15.5	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-6.0	V/ns
PD	Power Dissipation $(T_A = 25^{\circ}C)^*$	3.75	W	
	Power Dissipation $(T_C = 25^{\circ}C)$	155	W	
	- Derate above 25°C	1.03	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to +175	°C	
Τ _L	Maximum lead temperature for soldering, 1/8" from case for 5 seconds	300	°C	

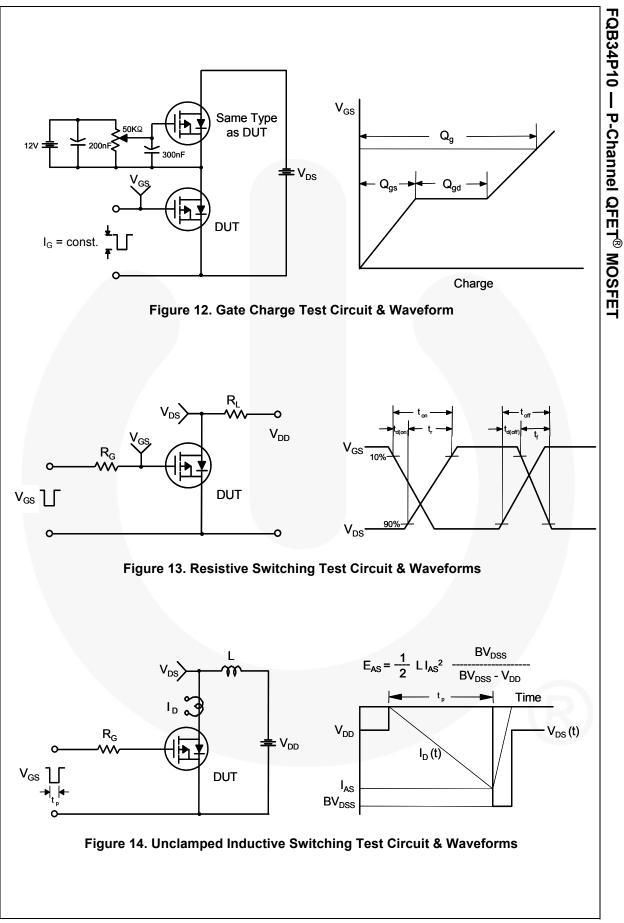
Thermal Characteristics

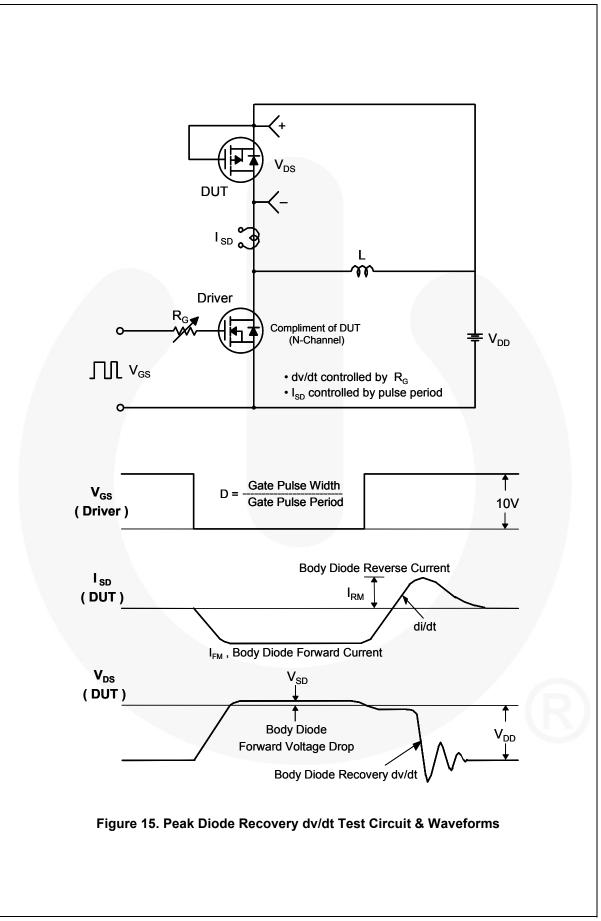
Symbol	Parameter	FQB34P10TM	Unit
R_{\thetaJC}	Thermal Resistance, Junction to Case, Max.	0.97	
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	62.5	°C/W
	Thermal Resistance, Junction to Ambient (*1 in ² Pad of 2-oz Copper), Max.	40]

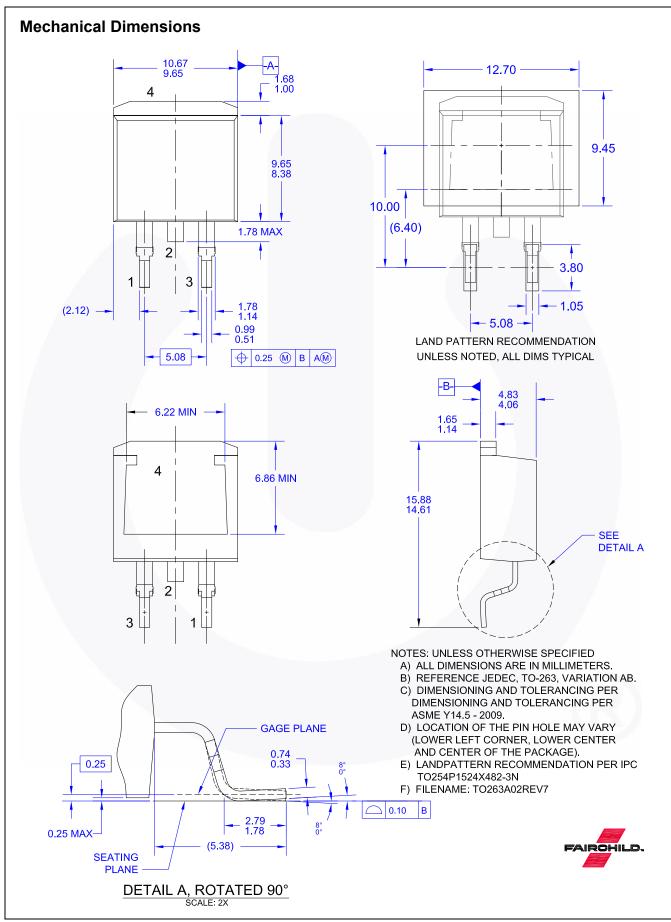
Part Number FQB34P10TM		Top Mark	Pack	age	Packing Method	Reel	Size	Tape Wi	dth C	Quantity
		FQB34P10	D ² -1	AK Tape and Reel		330 mm		24 mn	n 8	800 units
lectri	cal Cha	racteristics	T _C = 25°0	Cunless off	nerwise noted.					
Symbol		Parameter			Test Conditions		Min.	Тур.	Max.	Unit
Off Cha	aracterist	ice								
BV _{DSS}		Irce Breakdown Vo	Itage	V _{GS} =	0 V, I _D = -250 μA		-100			V
ΔBV _{DSS} /ΔTJ	Breakdow Coefficien	own Voltage Temperature		$I_D = -250 \ \mu\text{A}$, Referenced to 25°C			-0.1		V/°C	
DSS				-100 V, V _{GS} = 0 V				-1	μA	
	Zero Gale	Zero Gate Voltage Drain Current		20	-80 V, T _C = 150°C				-10	μA
GSSF	Gate-Bod	y Leakage Current	Forward	$V_{GS} = -25 V, V_{DS} = 0 V$					-100	nA
GSSR	Gate-Bod	y Leakage Current	Reverse	V _{GS} =	25 V, V _{DS} = 0 V				100	nA
On Cha	racterist	ics								
/ _{GS(th)}	Gate Thre	shold Voltage		V _{DS} =	V _{GS} , I _D = -250 μA		-2.0		-4.0	V
R _{DS(on)}	Static Dra On-Resist				-10 V, I _D = -16.75 A			0.049	0.06	Ω
ĴFS	Forward 1	ransconductance		V _{DS} =	-40 V, I _D = -16.75 A			23		S
Dynam	ic Chara	cteristics								
Siss	Input Cap		_	V	$-25 \sqrt{1} = 0 \sqrt{1}$			2240	2910	pF
Coss		apacitance	_	V _{DS} = -25 V, V _{GS} = 0 V, f = 1.0 MHz				730	950	pF
Prss		Fransfer Capacitan	ce				170	220	pF	
										1
d(on)		acteristics Delay Time	_					25	60	ns
a(on) r	Turn-On F	,	_	V _{DD} = -50 V, I _D = -33.5 A,				250	510	ns
d(off)		Delay Time	_	R _G = 2	25 Ω			160	330	ns
u(OII) f	Turn-Off F	,		-		(Note 4)		210	430	ns
λ _g	Total Gate			V -	-80 V, I _D = -33.5 A,			85	110	nC
Q_{gs}		rce Charge		V _{DS} =				15		nC
Ω _{gd}	Gate-Drai	9		•GS		(Note 4)		45		nC
							1	II		1
	1				cimum Ratings	-			00 5	
S		Continuous Drain-							-33.5	A
SM		Pulsed Drain-Sou			0 V, I _S = -33.5 A				-134	A
/ _{SD}		Irce Diode Forward	voltage		-				-4.0	V
rr C		Recovery Time		V _{GS} = 0 V, I _S = -33.5 A, dI _F / dt = 100 A/μs			160		ns	
2 _{rr}	Reverse F	Recovery Charge		ur _F / ut	_ 100 Λ/μδ			0.88		μC
$L = mH$, I_{A} $I_{SD} \le -33.5$	$_{\rm S}$ = -33.5A, V _{DD} 5 A, di/dt \leq 300	dth limited by maximum j $_{1} = -25 V, R_{G} = 25 \Omega$, star $A/\mu s$, $V_{DD} \leq BV_{DSS}$, st operating temperature.	ting T _J = 25°C							













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P-Channel QFET[®] MOSFET

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